74LVT126

3.3 V quad buffer; 3-state

Rev. 7 — 18 April 2024

Product data sheet

1. General description

The 74LVT126 is a quad buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). A LOW on nOE causes the outputs to assume a high impedance OFF-state. Bus hold data inputs eliminate the need for external pull-up resistors to define unused inputs. This device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- · Quad bus interface
- 3-state buffers
- Wide supply voltage range from 2.7 to 3.6 V
- Overvoltage tolerant inputs to 5.5 V
- BiCMOS high speed and output drive
- Output capability: +64 mA and -32 mA
- · Direct interface with TTL levels
- · Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Power-up 3-state
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 500 mA per JESD 78 Class II Level B
- Complies with JEDEC standard JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C

3. Ordering information

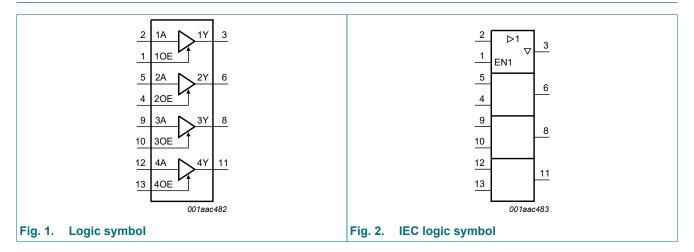
Table 1. Ordering information

| Type number | Package | | | | | | | |
|-------------|-------------------|----------|--|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74LVT126D | -40 °C to +85 °C | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | | | | |
| 74LVT126PW | -40 °C to +85 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | SOT402-1 | | | | |
| 74LVT126BQ | -40 °C to +85 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm | SOT762-1 | | | | |



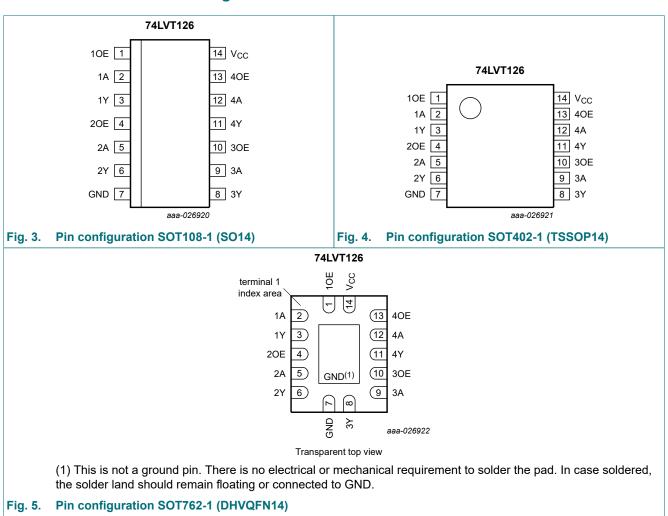
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4. Functional diagram



5. Pinning information

5.1. Pinning



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5.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|--------------------|--------------|----------------------|
| 10E, 20E, 30E, 40E | 1, 4, 10, 13 | output enable inputs |
| 1A, 2A, 3A, 4A | 2, 5, 9, 12 | data inputs |
| 1Y, 2Y, 3Y, 4Y | 3, 6, 8, 11 | data outputs |
| GND | 7 | ground (0 V) |
| V _{CC} | 14 | supply voltage |

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

| Input nOE | Output | |
|--------------|--------|----|
| nOE | nA | nY |
| Н | L | L |
| Н | Н | Н |
| L | X | Z |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|-----------------------------------|-----|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +4.6 | V |
| VI | input voltage | | [1] | -0.5 | +7.0 | V |
| Vo | output voltage | output in OFF-state or HIGH-state | [1] | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -50 | - | mA |
| I _{OK} | output clamping current | V _O < 0 V | | -50 | - | mA |
| Io | output current | output in LOW-state | | - | 128 | mA |
| | | output in HIGH-state | | - | -64 | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| Tj | junction temperature | | [2] | - | 150 | °C |

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

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8. Recommended operating conditions

Table 5. Operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|-------------------------------------|--------------------------------------|-----|-----|-----|------|
| V _{CC} | supply voltage | | 2.7 | - | 3.6 | V |
| VI | input voltage | | 0 | - | 5.5 | V |
| I _{OH} | HIGH-level output current | | -32 | - | - | mA |
| I _{OL} | LOW-level output current | none | - | - | 32 | mA |
| | | current duty cycle ≤ 50 %; f ≥ 1 kHz | - | - | 64 | mA |
| T _{amb} | ambient temperature | in free air | -40 | - | +85 | °C |
| Δt/ΔV | input transition rise and fall rate | outputs enabled | - | - | 10 | ns/V |

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Typ[1] | Max | Unit |
|-----------------------|------------------------------------|---|-----|-----------------------|-----------------------|------|------|
| V _{IK} | input clamping voltage | V _{CC} = 2.7 V; I _{IK} = -18 mA | | -1.2 | -0.9 | - | V |
| V _{IH} | HIGH-level input voltage | | | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | | | - | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _{CC} = 2.7 V to 3.6 V; I _{OH} = -100 μA | | V _{CC} - 0.2 | V _{CC} - 0.1 | - | V |
| | | V _{CC} = 2.7 V; I _{OH} = -8 mA | | 2.4 | 2.5 | - | V |
| | | V _{CC} = 3.0 V; I _{OH} = -32 mA | | 2.0 | 2.2 | - | V |
| V _{OL} | LOW-level output voltage | V _{CC} = 2.7 V; I _{OL} = 100 μA | | - | 0.1 | 0.2 | V |
| | | V _{CC} = 2.7 V; I _{OL} = 24 mA | | - | 0.3 | 0.5 | V |
| | | V _{CC} = 3.0 V; I _{OL} = 16 mA | | - | 0.25 | 0.4 | V |
| | | V _{CC} = 3.0 V; I _{OL} = 32 mA | | - | 0.3 | 0.5 | V |
| | | V _{CC} = 3.0 V; I _{OL} = 64 mA | | - | 0.4 | 0.55 | V |
| I _I | input leakage current | all input pins | | | | | |
| | | V _{CC} = 0 V or 3.6 V; V _I = 5.5 V | | - | 1 | 10 | μΑ |
| | | control pins | | | | | |
| | | V_{CC} = 3.6 V; V_I = V_{CC} or GND | | - | ±0.1 | ±1 | μA |
| | | data pins | | | | | |
| | | $V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC}$ | [2] | - | 0.1 | 1 | μA |
| | | V _{CC} = 3.6 V; V _I = 0 V | [2] | - | -1 | -5 | μA |
| I _{OFF} | power-off leakage current | $V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$ | | - | 1 | ±100 | μA |
| I _{BHL} | bus hold LOW current | V _{CC} = 3 V; V _I = 0.8 V | | 75 | 150 | - | μA |
| I _{BHH} | bus hold HIGH current | V _{CC} = 3 V; V _I = 2.0 V | | -75 | -150 | - | μA |
| I _{BHLO} | bus hold LOW overdrive current | V _{CC} = 3.6 V; V _I = 0 V to 3.6 V | [3] | 500 | - | - | μA |
| I _{внно} | bus hold HIGH overdrive current | V _{CC} = 3.6 V; V _I = 0 V to 3.6 V | [3] | - | - | -500 | μA |
| I _{EX} | external current | output in HIGH-state when V _O > V _{CC} ; V _O = 5.5 V; V _{CC} = 3.0 V | | - | 60 | 125 | μA |
| I _{O(pu/pd)} | power-up/power-down output current | $V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ nOE} = \text{don't care}$ | [4] | - | ±1 | ±100 | μΑ |

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| Symbol | Parameter | Conditions | | Min | Typ[1] | Max | Unit |
|------------------|---------------------------|--|-----|-----|--------|------|------|
| I _{OZ} | OFF-state output current | V _{CC} = 3.6 V | | | | | |
| | | output HIGH: V _O = 3.0 V | | - | 1 | 5 | μΑ |
| | | output LOW: V _O = 0.5 V | | - | -1 | -5 | μΑ |
| I _{CC} | supply current | V_{CC} = 3.6 V; V_I = GND or V_{CC} ; I_O = 0 A | | | | | |
| | | outputs HIGH | | - | 0.13 | 0.19 | mA |
| | | outputs LOW | | - | 2 | 7 | mA |
| | | outputs disabled | [5] | - | 0.13 | 0.19 | mA |
| ΔI _{CC} | additional supply current | per input pin; V _{CC} = 3 V to 3.6 V; one input at V _{CC} - 0.6 V and other inputs at V _{CC} or GND | [6] | - | 0.1 | 0.2 | mA |
| Cı | input capacitance | V _I = 0 V or V _{CC} | | - | 4 | - | pF |
| Co | output capacitance | outputs disabled; V _O = 0 V or 3.0 V | | - | 8 | - | pF |

- [1] Typical values are measured at nominal V_{CC} and T_{amb} = 25 °C.
- [2] Unused pins at V_{CC} or GND.
- [3] This is the bus hold overdrive current required to force the input to the opposite logic state.
- [4] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From $V_{CC} = 1.2$ V to $V_{CC} = 3.3$ V \pm 0.3 V a transition time of 100 μ s is permitted. This parameter is valid for $T_{amb} = 25$ °C only.
- [5] Measured with outputs pulled up to V_{CC} or GND.
- [6] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 8.

| Symbol | Parameter | Conditions | T _{aml} | T _{amb} = -40 °C to +85 °C | | | |
|------------------|-------------------------------------|--|------------------|-------------------------------------|-----|----|--|
| | | | Min | Typ[1] | Max | | |
| t _{PLH} | LOW to HIGH | nA to nY; see Fig. 6 | | | | | |
| | propagation delay | V _{CC} = 2.7 V | - | - | 4.5 | ns | |
| | | V _{CC} = 3.3 V ± 0.3 V | 1.0 | 2.3 | 3.8 | ns | |
| t _{PHL} | HIGH to LOW | nA to nY; see Fig. 6 | | | | | |
| | propagation delay | V _{CC} = 2.7 V | - | - | 4.4 | ns | |
| | | V _{CC} = 3.3 V ± 0.3 V | 1.0 | 2.4 | 3.9 | ns | |
| t _{PZH} | OFF-state to HIGH propagation delay | nOE to nY; see Fig. 7 | | | | | |
| | | V _{CC} = 2.7 V | - | - | 6.1 | ns | |
| | | V _{CC} = 3.3 V ± 0.3 V | 1.0 | 3.6 | 5.4 | ns | |
| t _{PZL} | OFF-state to LOW propagation delay | nOE to nY; see Fig. 7 | | | | | |
| | | V _{CC} = 2.7 V | - | - | 5.8 | ns | |
| | | V _{CC} = 3.3 V ± 0.3 V | 1.1 | 3.6 | 5.2 | ns | |
| t _{PHZ} | HIGH to OFF-state | nOE to nY; see Fig. 7 | | | | | |
| | propagation delay | V _{CC} = 2.7 V | - | - | 4.3 | ns | |
| | | V _{CC} = 3.3 V ± 0.3 V | 1.0 | 2.2 | 3.8 | ns | |
| t _{PLZ} | LOW to OFF-state | nOE to nY; see Fig. 7 | | | | | |
| | propagation delay | V _{CC} = 2.7 V | - | - | 6.1 | ns | |
| | | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 1.3 | 3.6 | 5.5 | ns | |

^[1] Typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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10.1. Waveforms and test circuit

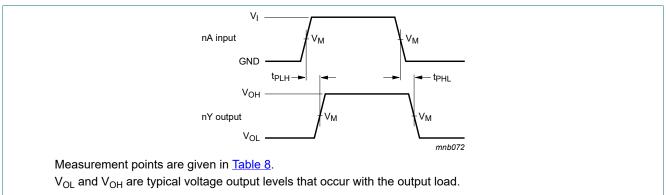


Fig. 6. Propagation delay input (nA) to output (nY)

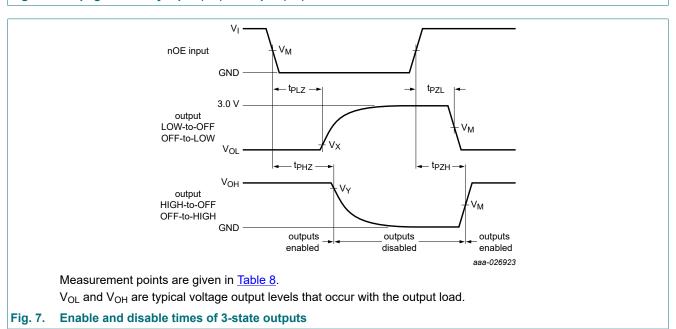
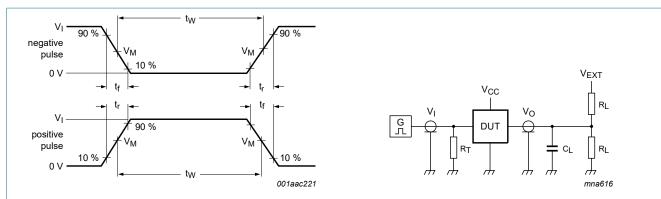


Table 8. Measurement points

| Input | Output | | | | |
|---------|----------------|-------------------------|-------------------------|--|--|
| V_{M} | V _M | V _X | V _Y | | |
| 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} - 0.3 V | | |

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Test data is given in Table 9.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = Test voltage for switching times.

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

| Input | | | Load | | V _{EXT} | | | |
|---------|----------------|----------------|---------------------------------|-------|------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V_{l} | f _i | t _W | t _r , t _f | CL | R_L | t _{PHZ} , t _{PZH} | t _{PLZ} , t _{PZL} | t _{PLH} , t _{PHL} |
| 2.7 V | ≤ 10 MHz | 500 ns | ≤ 2.5 ns | 50 pF | 500 Ω | GND | 6 V | open |

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11. Package outline

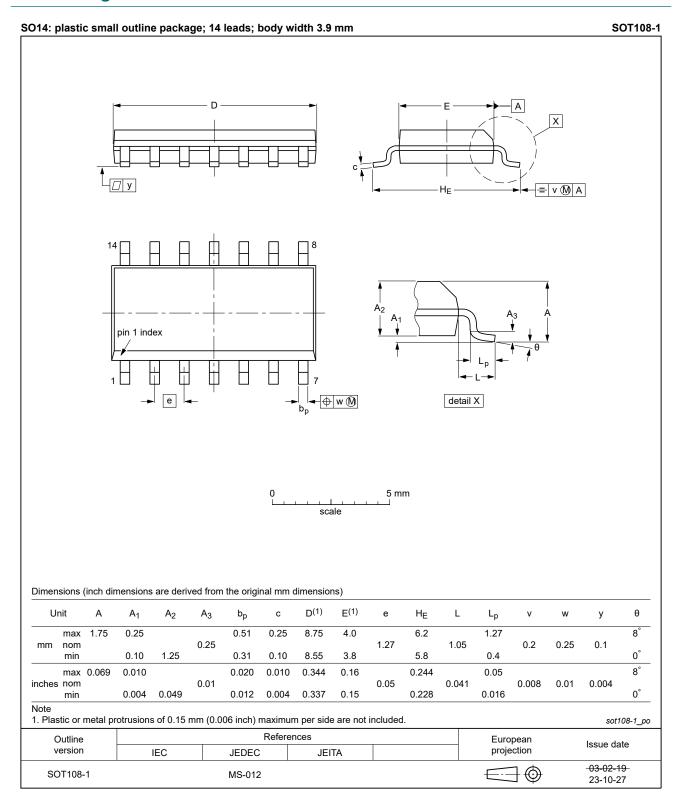


Fig. 9. Package outline SOT108-1 (SO14)

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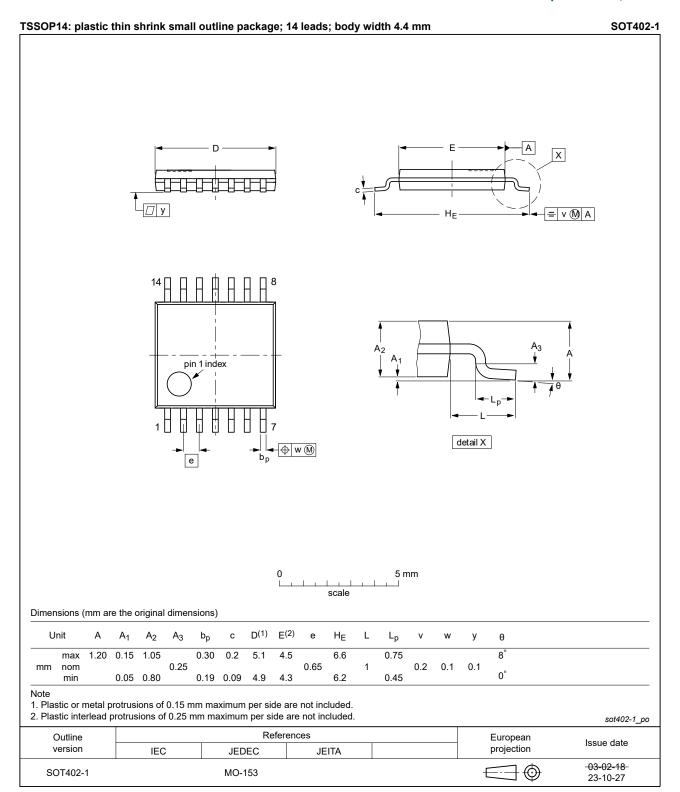


Fig. 10. Package outline SOT402-1 (TSSOP14)

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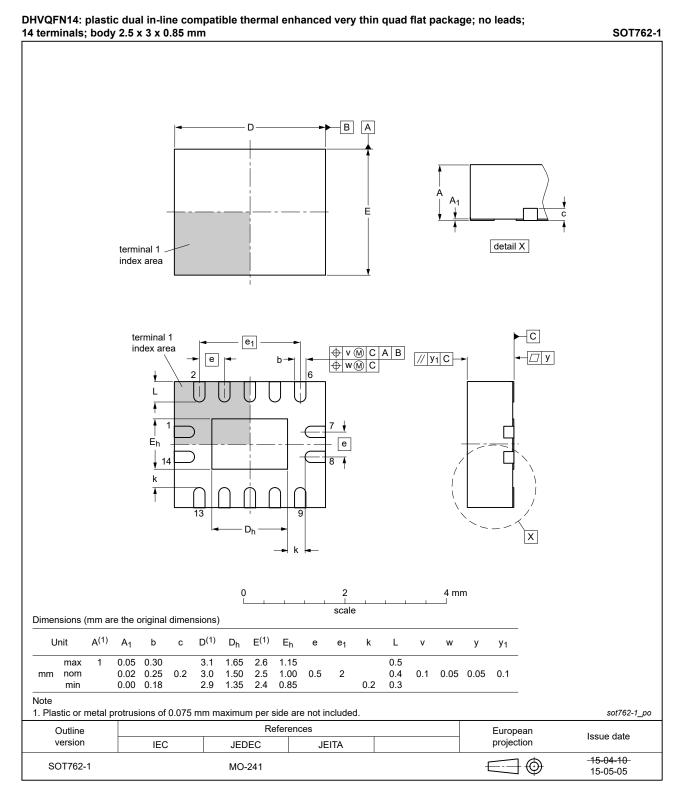


Fig. 11. Package outline SOT762-1 (DHVQFN14)

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12. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| BiCMOS | Bipolar Complementary Metal Oxide Semiconductor |
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| TTL | Transistor-Transistor Logic |

13. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
|----------------|--|--|---------------|--------------|--|--|--|--|
| 74LVT126 v.7 | 20240418 | Product data sheet | - | 74LVT126 v.6 | | | | |
| Modifications: | Fig. 9, Fig. 10: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. Section 2: ESD specification updated according to the latest JEDEC standard. | | | | | | | |
| 74LVT126 v.6 | 20210727 | Product data sheet | - | 74LVT126 v.5 | | | | |
| Modifications: | • | Type number 74LVT126DB (SOT337-1/SSOP14) removed. Section 1 and Section 2 updated. | | | | | | |
| 74LVT126 v.5 | 20170614 | Product data sheet | - | 74LVT126 v.4 | | | | |
| Modifications: | guidelines | t of this data sheet has be of Nexperia. s have been adapted to the | · · | • | | | | |
| 74LVT126 v.4 | 20050211 | Product data sheet | - | 74LVT126 v.3 | | | | |
| Modifications: | and inform | The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors. Fig. 5: added note 1. | | | | | | |
| 74LVT126 v.3 | 20040624 | Product data sheet | - | 74LVT126 v.2 | | | | |
| 74LVT126 v.2 | 19980219 | Product specification | - | 74LVT126 v.1 | | | | |
| 74LVT126 v.1 | 19951221 | - | - | - | | | | |

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Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
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